

# B105S thru B110S

### SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIERS

### REVERSE VOLTAGE - 50 to 1000 Volts FORWARD CURRENT - 1.0 Ampere

#### MBS FEATURES Rating to 1000V PRV .275(7.0)MAX .067(1.7) Ideal for printed circuit board .165(4.2) .057(1.3) .146(3.7) Reliable low cost construction utilizing .051(1.3) .035(0.9) molded plastic technique results in inexpensive product Lead tin plated copper .014(.35) .043(1.1) .006(.15) .027(0.7) .031(0.8) **MECHANICAL DATA** .019(0.5) .067(1.7) .106(2.7) .057(1.3) .09(2.3) Polarity:Symbol molded on body •Weight: 0.0044 ounces,0.125 grams .193(4.9) Mounting position :Any .177(4.5) .106(2.7) .09(2.3) .008(0.2)

### Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25  $^\circ\!\!\!\mathrm{C}$  ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	B105S	B11S	B12S	B14S	B16S	B18S	B110S	UNIT
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	Vrms	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current (Note 1) @Ta=40 °C	I(AV)	1							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load(JEDEC Method)	IFSM	30							A
Peak Forward Voltage at 1.0A DC	VF	1.1						V	
Maximum DC Reverse Current@TJ=25°Cat Rated DC Bolcking Voltage@TJ=125°C	lr	5.0 500							μA
Typical Junction Capacitance Per Element (Note2)	Сл	15							pF
Typical Thermal Resistance (Note3)	Rejc	75						°C/W	
Operating Temperature Range	TJ	-55 to +150							°C
Storage Temperature Range	Tstg	-55 to +150							°C

NOTES:1.Mounted on P.C. board.

2.Measured at1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to case

## **RATING AND CHARACTERTIC CURVES** B105S thru B110S



